INTEGRATED CIRCUITS

DATA SHEET

74HC08; 74HCT08 Quad 2-input AND gate

Product specification Supersedes data of 1990 Dec 01





Quad 2-input AND gate

74HC08; 74HCT08

FEATURES

- · Complies with JEDEC standard no. 8-1A
- ESD protection: HBM EIA/JESD22-A114-A exceeds 2000 V MM EIA/JESD22-A115-A exceeds 200 V.
- Specified from -40 to +85 °C and -40 to +125 °C.

DESCRIPTION

The 74HC/HCT08 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A. The 74HC/HCT08 provide the 2-input AND function.

QUICK REFERENCE DATA

GND = 0 V; T_{amb} = 25 °C; t_r = t_f = 6 ns.

| SYMBOL | DADAMETED | CONDITIONS | TYF | UNUT | |
|------------------------------------|--|---|--------|---------|------|
| | PARAMETER | CONDITIONS | 74HC08 | 74HCT08 | UNIT |
| t _{PHL} /t _{PLH} | propagation delay nA, nB to nY | C _L = 15 pF; V _{CC} = 5 V | 7 | 11 | ns |
| Cı | input capacitance | | 3.5 | 3.5 | pF |
| C _{PD} | power dissipation capacitance per gate | notes 1 and 2 | 10 | 20 | pF |

Notes

1. C_{PD} is used to determine the dynamic power dissipation (P_D in ∞W).

$$P_D = C_{PD} \cdot V_{CC}^2 \cdot f_i \cdot N + \Sigma (C_L \cdot V_{CC}^2 \cdot f_o)$$
 where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volts;

N = total load switching outputs;

 $\Sigma(C_L \cdot V_{CC}^2 \cdot f_o)$ = sum of the outputs.

2. For 74HC08: the condition is V_I = GND to V_{CC} .

For 74HCT08: the condition is V_I = GND to V_{CC} - 1.5 V.

FUNCTION TABLE

| INF | TUT | OUTPUT |
|-----|-----|----------------|
| nA | nB | nY |
| L | L | Ĺ |
| L | Н | L _Q |
| Н | L | L |
| Н | Н | Н |

Note

1. H = HIGH voltage level;

L = LOW voltage level.

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ORDERING INFORMATION

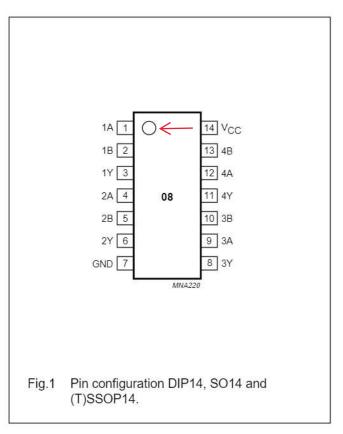
| TVDE NUMBER | PACKAGE | | | | | | | | |
|-------------|-------------------|------|----------|----------|----------|--|--|--|--|
| TYPE NUMBER | TEMPERATURE RANGE | PINS | PACKAGE | MATERIAL | CODE | | | | |
| 74HC08N | -40 to +125 °C | 14 | DIP14 | plastic | SOT27-1 | | | | |
| 74HCT08N | -40 to +125 °C | 14 | DIP14 | plastic | SOT27-1 | | | | |
| 74HC08D | -40 to +125 °C | 14 | SO14 | plastic | SOT108-1 | | | | |
| 74HCT08D | -40 to +125 °C | 14 | SO14 | plastic | SOT108-1 | | | | |
| 74HC08DB | -40 to +125 °C | 14 | SSOP14 | plastic | SOT337-1 | | | | |
| 74HCT08DB | -40 to +125 °C | 14 | SSOP14 | plastic | SOT337-1 | | | | |
| 74HC08PW | -40 to +125 °C | 14 | TSSOP14 | plastic | SOT402-1 | | | | |
| 74HCT08PW | -40 to +125 °C | 14 | TSSOP14 | plastic | SOT402-1 | | | | |
| 74HC08BQ | -40 to +125 °C | 14 | DHVQFN14 | plastic | SOT762-1 | | | | |
| 74HCT08BQ | -40 to +125 °C | 14 | DHVQFN14 | plastic | SOT762-1 | | | | |

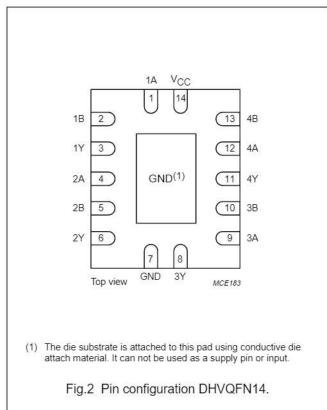
PINNING

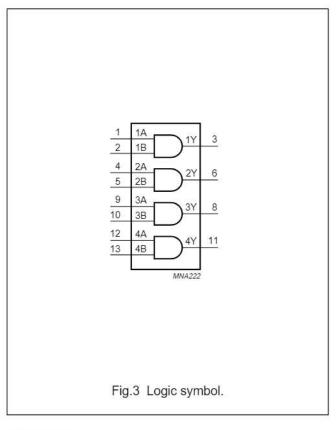
| PIN | SYMBOL | DESCRIPTION |
|-----|-----------------|----------------|
| 1 | 1A | data input |
| 2 | 1B | data input |
| 3 | 1Y | data output |
| 4 | 2A | data input |
| 5 | 2B | data input |
| 6 | 2Y | data output |
| 7 | GND | ground (0 V) |
| 8 | 3Y | data output |
| 9 | 3A | data input |
| 10 | 3B | data input |
| 11 | 4Y | data output |
| 12 | 4A | data input |
| 13 | 4B | data input |
| 14 | V _{CC} | supply voltage |

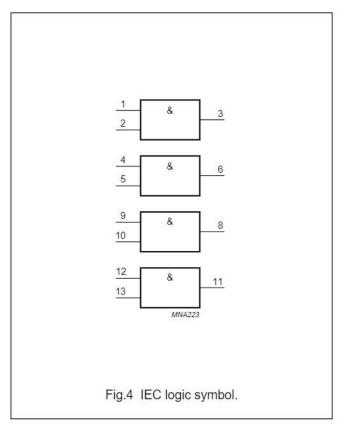
Quad 2-input AND gate

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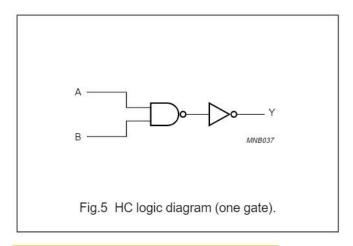


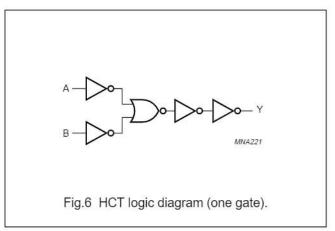




Quad 2-input AND gate

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RECOMMENDED OPERATING CONDITIONS

| SYMBOL | DADAMETED | CONDITIONS | 74HC08 | | | 74HCT08 | | | UNIT |
|---------------------------------|------------------------|--|--------|------|-----------------|---------|------|-----------------|------|
| | PARAMETER | | MIN. | TYP. | MAX. | MIN. | TYP. | MAX. | UNII |
| Vcc | supply voltage | | 2.0 | 5.0 | 6.0 | 4.5 | 5.0 | 5.5 | ٧ |
| VI | input voltage | | 0 | - | Vcc | 0 | - | Vcc | ٧ |
| Vo | output voltage | | 0 | - | V _{CC} | 0 | - | V _{CC} | ٧ |
| T _{amb} | ambient temperature | see DC and AC characteristics per device | -40 | +25 | +125 | -40 | +25 | +125 | °C |
| t _r , t _f | input rise and fall | V _{CC} = 2.0 V | - | - | 1000 | - | | = | ns |
| | times | V _{CC} = 4.5 V | - | 6.0 | 500 | - | 6.0 | 500 | ns |
| | | V _{CC} = 6.0 V | - | - | 400 | - | = | - | ns |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134); voltages are referenced to GND (ground = 0 V).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------------------------|--------------------------------|--|------|------|------|
| V _{CC} | supply voltage | | -0.5 | +7.0 | V |
| I _{IK} | input diode current | $V_1 < -0.5 \text{ V or } V_1 > V_{CC} + 0.5 \text{ V}$ | - | ±20 | mA |
| lok | output diode current | $V_{\rm O}$ < -0.5 V or $V_{\rm O}$ > $V_{\rm CC}$ + 0.5 V | = | ±20 | mA |
| l _o | output source or sink current | -0.5 V < V _O < V _{CC} + 0.5 V | - | ±25 | mA |
| I _{CC} , I _{GND} | V _{CC} or GND current | | - | ±50 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | power dissipation | | 53 | | |
| | DIP14 package | $T_{amb} = -40 \text{ to } +125 ^{\circ}\text{C}; \text{ note } 1$ | -29 | 750 | mW |
| | other packages | $T_{amb} = -40 \text{ to } +125 ^{\circ}\text{C}; \text{ note } 2$ | - | 500 | mW |

Notes

- 1. For DIP14 packages: above 70 °C derate linearly with 12 mW/K.
- 2. For SO14 packages: above 70 °C derate linearly with 8 mW/K.

For SSOP14 and TSSOP14 packages: above 60 °C derate linearly with 5.5 mW/K.

For DHVQFN14 packages: above 60 °C derate linearly with 4.5 mW/K.

Quad 2-input AND gate

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DC CHARACTERISTICS

Family 74HC08

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| CVMDOL | DADAMETED | TEST CONDITIO | NS | MINI | TVD | MAY | LINUT | |
|-------------------------|----------------------------|---|---------------------|------|------|-------|-------|--|
| SYMBOL | PARAMETER | OTHER | V _{CC} (V) | MIN. | TYP. | MAX. | UNIT | |
| T _{amb} = 25 ° | Ċ | | | | | 1 | • | |
| V _{IH} | HIGH-level input voltage | | 2.0 | 1.5 | 1.2 | === | V | |
| | | | 4.5 | 3.15 | 2.4 | - | V | |
| | | | 6.0 | 4.2 | 3.2 | - | V | |
| V _{IL} | LOW-level input voltage | | 2.0 | _ | 0.8 | 0.5 | V | |
| | 68 5005 | | 4.5 | - | 2.1 | 1.35 | V | |
| | | | 6.0 | - | 2.8 | 1.8 | V | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | * | | | |
| 300 m 1 m | | I _O = −20 ∞A | 2.0 | 1.9 | 2.0 | == | V | |
| | | I _O = −20 ∝A | 4.5 | 4.4 | 4.5 | 20 | V | |
| | | $I_{O} = -4.0 \text{ mA}$ | 4.5 | 3.98 | 4.32 | | V | |
| | | I _O = −20 ∝A | 6.0 | 5.9 | 6.0 | | V | |
| | | I _O = −5.2 mA | 6.0 | 5.48 | 5.81 | -8 | V | |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | | |
| | | I _O = 20 ∞A | 2.0 | - | 0 | 0.1 | V | |
| | | I _O = 20 ∝A | 4.5 | = | 0 | 0.1 | V | |
| | | $I_{O} = 4.0 \text{ mA}$ | 4.5 | _ | 0.15 | 0.26 | V | |
| | | I _O = 20 ∞A | 6.0 | - | 0 | 0.1 | V | |
| | | I _O = 5.2 mA | 6.0 | - | 0.16 | 0.26 | V | |
| ILI | input leakage current | V _I = V _{CC} or GND | 6.0 | - | 0.1 | ±.0.1 | ∞A | |
| loz | 3-state output OFF current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$ | 6.0 | | = | ±.0.5 | αA | |
| Icc | quiescent supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ | 6.0 | | 7700 | 2 | ∞A | |

Quad 2-input AND gate

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| OVMDOL | PARAMETER | TEST CONDITIO | NS | NAINI | TVD | MAX. | UNIT |
|------------------------|----------------------------|---|---------------------|--------------------|-------------------|---|------|
| SYMBOL | FARAMETER | OTHER | V _{CC} (V) | MIN. | TYP. | IVIAA. | ONL |
| T _{amb} = -40 | to +85 °C | | | | M. | | |
| V _{IH} | HIGH-level input voltage | | 2.0 | 1.5 | - | - | V |
| | 921 2-489 | | 4.5 | 3.15 | - | - | V |
| | | | 6.0 | 4.2 | - | - | V |
| V _{IL} | LOW-level input voltage | | 2.0 | - | - | 0.5 | V |
| | | | 4.5 | - | - | 1.35 | V |
| | | | 6.0 | 1 11 11 | | 1.8 | V |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | 2 |
| | 46 (199) | I _O = −20 ∝A | 2.0 | 1.9 | _ | == | V |
| | | I _O = −20 ∞A | 4.5 | 4.4 | 1-2 | ======================================= | V |
| | | $I_{O} = -4.0 \text{ mA}$ | 4.5 | 3.84 | | | V |
| | | I _O = −20 ∞A | 6.0 | 5.9 | | 2 | V |
| | | I _O = −5.2 mA | 6.0 | 5.34 | . 2: | === | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | - | |
| | 1 904 30594 | I _O = 20 ∞A | 2.0 | _ | - | 0.1 | V |
| | | I _O = 20 ∞A | 4.5 | _ | - | 0.1 | V |
| | | $I_{O} = 4.0 \text{ mA}$ | 4.5 | - | | 0.33 | V |
| | | I _O = 20 ∞A | 6.0 | | | 0.1 | V |
| | | $I_{O} = 5.2 \text{ mA}$ | 6.0 | 170 4 | 1 11 2 | 0.33 | V |
| I _{LI} | input leakage current | V _I = V _{CC} or GND | 6.0 | | 100 0 | ±1.0 | ×Α |
| l _{OZ} | 3-state output OFF current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$ | 6.0 | - | - | ±.5.0 | «Α |
| I _{cc} | quiescent supply current | $V_1 = V_{CC}$ or GND; $I_0 = 0$ | 6.0 | - | - | 20 | «Α |

Quad 2-input AND gate

74HC08; 74HCT08

| OVMBOL | DADAMETED | TEST CONDITIO | NS | NAUNT . | T/D | | |
|------------------------|----------------------------|---|---------------------|---------|--|-------------|------|
| SYMBOL | PARAMETER | OTHER | V _{cc} (V) | MIN. | TYP. | MAX. | UNIT |
| T _{amb} = -40 | to +125 °C | | | dia. | to the state of th | *** | |
| V _{IH} | HIGH-level input voltage | | 2.0 | 1.5 | - | - | V |
| | 721 25027 | | 4.5 | 3.15 | - | = | V |
| | | | 6.0 | 4.2 | - | - | V |
| V _{IL} | LOW-level input voltage | | 2.0 | - | - | 0.5 | V |
| | | | 4.5 | - | - | 1.35 | V |
| | | | 6.0 | - | i a s | 1.8 | V |
| V _{OH} | HIGH-level output voltage | V _I = V _{IH} or V _{IL} | | | | | 2 |
| | 100 | I _O = −20 ∝A | 2.0 | 1.9 | - | - | V |
| | | I _O = −20 ∝A | 4.5 | 4.4 | <u>=</u> : | ==3 | V |
| | | $I_{O} = -4.0 \text{ mA}$ | 4.5 | 3.7 | - | | V |
| | | I _O = −20 ∝A | 6.0 | 5.9 | - | - | V |
| | | $I_{\rm O}$ = -5.2 mA | 6.0 | 5.2 | | | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | 1 112 | I _O = 20 ∞A | 2.0 | _ | _ | 0.1 | V |
| | | I _O = 20 ∝A | 4.5 | _ | _ | 0.1 | V |
| | | $I_{O} = 4.0 \text{ mA}$ | 4.5 | - | - | 0.4 | V |
| | | I _O = 20 ∞A | 6.0 | - | - | 0.1 | V |
| | | I _O = 5.2 mA | 6.0 | | . | 0.4 | V |
| I _{LI} | input leakage current | V _I = V _{CC} or GND | 6.0 | | 1 | ±1.0 | ×Α |
| l _{OZ} | 3-state output OFF current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND}$ | 6.0 | - | - | ±10.0 | xΑ |
| Icc | quiescent supply current | $V_1 = V_{CC}$ or GND; $I_0 = 0$ | 6.0 | _ | _ | 40 | «Α |

Quad 2-input AND gate

74HC08; 74HCT08

Family 74HCT08

At recommended operating conditions; voltages are referenced to GND (ground = 0).

| OVMBOL | DA DAMETED | TEST CONDI | BAIN | TVD | MAN | | |
|-------------------------|-------------------------------------|---|---------------------|------|------|-----------------|------|
| SYMBOL | PARAMETER | OTHER | V _{CC} (V) | MIN. | TYP. | MAX. | UNIT |
| T _{amb} = 25 ° | Ċ | | • | | | | |
| V _{IH} | HIGH-level input voltage | | 4.5 to 5.5 | 2.0 | 1.6 | T | ٧ |
| V _{IL} | LOW-level input voltage | | 4.5 to 5.5 | - | 1.2 | 0.8 | ٧ |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | |
| | | I _O = -20 ∞A | 4.5 | 4.4 | 4.5 | - -0 | V |
| | | $I_{O} = -4.0 \text{ mA}$ | 4.5 | 3.84 | 4.32 | - | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | |
| | 907 (6.5%) | I _O = 20 ∞A | 4.5 | - | 0 | 0.1 | ٧ |
| | | $I_{O} = 4.0 \text{ mA}$ | 4.5 | - | 0.15 | 0.26 | V |
| I _{LI} | input leakage current | $V_I = V_{CC}$ or GND | 5.5 | - | | ±0.1 | αA |
| l _{oz} | 3-state output OFF current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $I_O = 0$ | 5.5 | - | = | ±0.5 | ∞A |
| I _{CC} | quiescent supply current | $V_1 = V_{CC}$ or GND; $I_0 = 0$ | 5.5 | | =: | 2 | xΑ |
| Δl _{CC} | additional supply current per input | $V_1 = V_{CC} - 2.1 V;$ $I_0 = 0$ | 4.5 to 5.5 | - | 60 | 216 | xΑ |
| T _{amb} = -40 | to +85 °C | ñ- | 10) | 10 | 1): | | |
| V _{IH} | HIGH-level input voltage | | 4.5 to 5.5 | 2.0 | = | _ | V |
| V _{IL} | LOW-level input voltage | | 4.5 to 5.5 | - | - | 0.8 | ٧ |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | |
| | | I _O = −20 ∝A | 4.5 | 4.4 | - | | V |
| | | $I_{O} = -4.0 \text{ mA}$ | 4.5 | 3.84 | - | ₩. | V |
| V _{OL} | LOW-level output voltage | V _I = V _{IH} or V _{IL} | | | | | |
| | | I _O = 20 ∞A | 4.5 | - | - | 0.1 | V |
| | | $I_{O} = 4.0 \text{ mA}$ | 4.5 | - | - | 0.33 | V |
| ILI | input leakage current | $V_I = V_{CC}$ or GND | 5.5 | - | - | ±1.0 | ∞A |
| l _{oz} | 3-state output OFF current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $I_O = 0$ | 5.5 | - | - | ±5.0 | ∝A |
| Icc | quiescent supply current | $V_I = V_{CC}$ or GND; $I_O = 0$ | 5.5 | - | - | 20 | ∞A |
| Δl _{CC} | additional supply current per input | $V_1 = V_{CC} - 2.1 \text{ V};$ $I_0 = 0$ | 4.5 to 5.5 | - | - | 270 | αA |

Quad 2-input AND gate

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| OVMBOL | PARAMETER | TEST CONDI | MINI | TVD | MAY | LINIT | |
|------------------------|-------------------------------------|---|---------------------|------|------|-------|------|
| SYMBOL | PARAMETER | OTHER | V _{CC} (V) | MIN. | TYP. | MAX. | UNIT |
| T _{amb} = -40 | to +125 °C | | l ic | | | **** | |
| V _{IH} | HIGH-level input voltage | | 4.5 to 5.5 | 2.0 | - | - | ٧ |
| V _{IL} | LOW-level input voltage | | 4.5 to 5.5 | - | - | 0.8 | ٧ |
| V _{OH} | HIGH-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | |
| | | I _O = −20 ∞A | 4.5 | 4.4 | | | V |
| | | $I_0 = -4.0 \text{ mA}$ | 4.5 | 3.7 | | | V |
| V _{OL} | LOW-level output voltage | $V_I = V_{IH}$ or V_{IL} | | | | | |
| | | I _O = 20 ∞A | 4.5 | - | - | 0.1 | V |
| | | I _O = 4.0 mA | 4.5 | = | _ | 0.4 | V |
| ILI | input leakage current | V _I = V _{CC} or GND | 5.5 | _ | = | ±1.0 | αA |
| l _{OZ} | 3-state output OFF current | $V_I = V_{IH} \text{ or } V_{IL};$ $V_O = V_{CC} \text{ or GND};$ $I_O = 0$ | 5.5 | - | - | ±10 | ∝A |
| Icc | quiescent supply current | $V_1 = V_{CC}$ or GND; $I_0 = 0$ | 5.5 | - | | 40 | ∝A |
| ΔI_{CC} | additional supply current per input | $V_1 = V_{CC} - 2.1 V;$ $I_0 = 0$ | 4.5 to 5.5 | | - | 294 | ∞A |

Quad 2-input AND gate

74HC08; 74HCT08

AC CHARACTERISTICS

Family 74HC08

GND = 0 V; $t_f = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$.

| OVMBO! | DADAMETED | TEST CONDI | TIONS | | T/D | MAY | |
|------------------------------------|---|------------------|---------------------|-----------------|------|------|------|
| SYMBOL | PARAMETER | WAVEFORMS | V _{CC} (V) | MIN. | TYP. | MAX. | UNIT |
| T _{amb} = 25 °C | Ċ | | | , | | | |
| t _{PHL} /t _{PLH} | propagation delay nA, | see Figs 7 and 8 | 2.0 | ·- | 25 | 90 | ns |
| | nB to nY | | 4.5 | 855 | 9 | 18 | ns |
| | | | 6.0 | = | 7 | 15 | ns |
| t _{THL} /t _{TLH} | output transition time | see Figs 7 and 8 | 2.0 | - | 19 | 75 | ns |
| | 741 | -270 | 4.5 | - | 7 | 15 | ns |
| | | | 6.0 | - | 6 | 13 | ns |
| T _{amb} = -40 | to +85 °C | | | | | | |
| t _{PHL} /t _{PLH} | propagation delay nA, | see Figs 7 and 8 | 2.0 | - | | 115 | ns |
| | nB to nY | | 4.5 | 1 2. | - | 23 | ns |
| | | | 6.0 | - | - | 20 | ns |
| t _{THL} /t _{TLH} | output transition time | see Figs 7 and 8 | 2.0 | ~ | - | 95 | ns |
| | 34 | | 4.5 | - | - | 19 | ns |
| | | | 6.0 | - | - | 16 | ns |
| T _{amb} = -40 | to +125 °C | | | , | | | |
| t _{PHL} /t _{PLH} | propagation delay nA, | see Figs 7 and 8 | 2.0 | a=. | i | 135 | ns |
| | nB to nY | | 4.5 | = | - | 27 | ns |
| | | | 6.0 | - | = | 23 | ns |
| t _{THL} /t _{TLH} | output transition time | see Figs 7 and 8 | 2.0 | = | - | 110 | ns |
| | \$ Page 10 Page | | 4.5 | <u> </u> | - | 22 | ns |
| | | | 6.0 | - | - | 19 | ns |

Quad 2-input AND gate

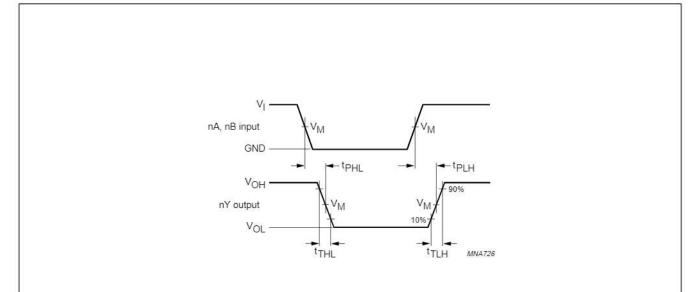
74HC08; 74HCT08

Family 74HCT08

GND = 0 V; $t_f = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$.

| 0\/4501 | DADAMETED | TEST CONDI | TIONS | | T/D | NA V | |
|------------------------------------|-----------------------------------|------------------|---------------------|----------|------|------|-------|
| SYMBOL | PARAMETER | WAVEFORMS | V _{CC} (V) | MIN. | TYP. | MAX. | UNIT |
| T _{amb} = 25 °C | Ċ | | | • | | · | |
| t _{PHL} /t _{PLH} | propagation delay nA, nB to nY | see Figs 7 and 8 | 4.5 | <u>-</u> | 14 | 24 | ns |
| t _{THL} /t _{TLH} | output transition time | see Figs 7 and 8 | 4.5 | = | 7 | 15 | ns |
| T _{amb} = -40 | to +85 °C | • | | | | | _ |
| t _{PHL} /t _{PLH} | propagation delay nA, nB to nY | see Figs 7 and 8 | 4.5 | - | - | 30 | ns |
| t _{THL} /t _{TLH} | output transition time | see Figs 7 and 8 | 4.5 | - | - | 19 | ns |
| T _{amb} = -40 | to +125 °C | i.i. | in . | | 24. | | die . |
| t _{PHL} /t _{PLH} | propagation delay nA, nB to nY | see Figs 7 and 8 | 4.5 | - | - | 36 | ns |
| t _{THL} /t _{TLH} | output transition time | see Figs 7 and 8 | 4.5 | - | - | 22 | ns |

AC WAVEFORMS

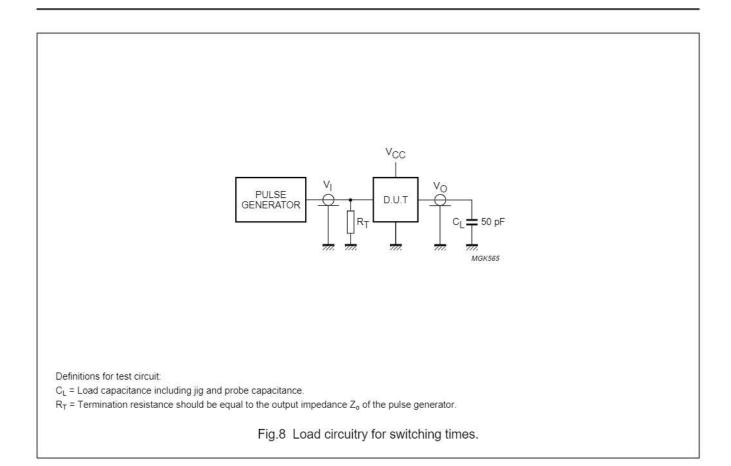


74HC08: $V_M = 50\%$; $V_I = GND$ to V_{CC} . 74HCT08: $V_M = 1.3$ V; $V_I = GND$ to 3 V.

Fig.7 Waveforms showing the input (nA, nB) to output (nY) propagation delays and the output transition times.

Quad 2-input AND gate

74HC08; 74HCT08



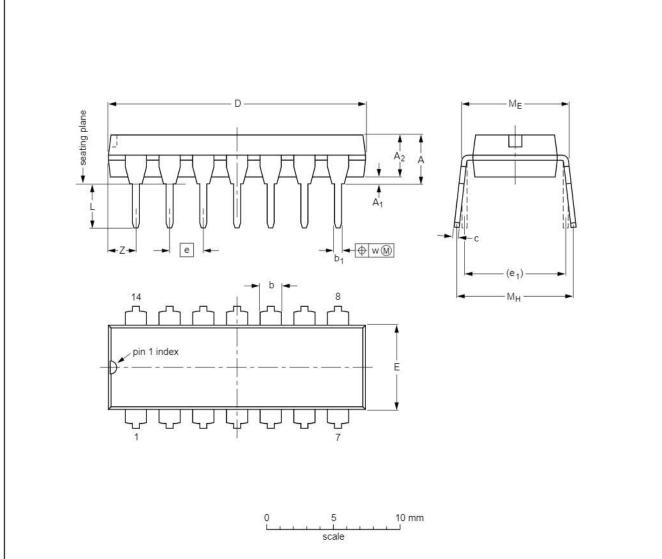
Quad 2-input AND gate

74HC08; 74HCT08

PACKAGE OUTLINES

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ min. | A ₂ max. | b | b ₁ | С | D (1) | E (1) | e | e ₁ | L | ME | M _H | w | Z (1) max. |
|--------|-----------|------------------------|------------------------|----------------|----------------|----------------|----------------|--------------|------|----------------|--------------|--------------|----------------|-------|---------------|
| mm | 4.2 | 0.51 | 3.2 | 1.73 1.13 | 0.53 0.38 | 0.36 0.23 | 19.50 18.55 | 6.48 6.20 | 2.54 | 7.62 | 3.60 3.05 | 8.25 7.80 | 10.0 8.3 | 0.254 | 2.2 |
| inches | 0.17 | 0.02 | 0.13 | 0.068 0.044 | 0.021 0.015 | 0.014 0.009 | 0.77 0.73 | 0.26 0.24 | 0.1 | 0.3 | 0.14 0.12 | 0.32 0.31 | 0.39 0.33 | 0.01 | 0.087 |

Note

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

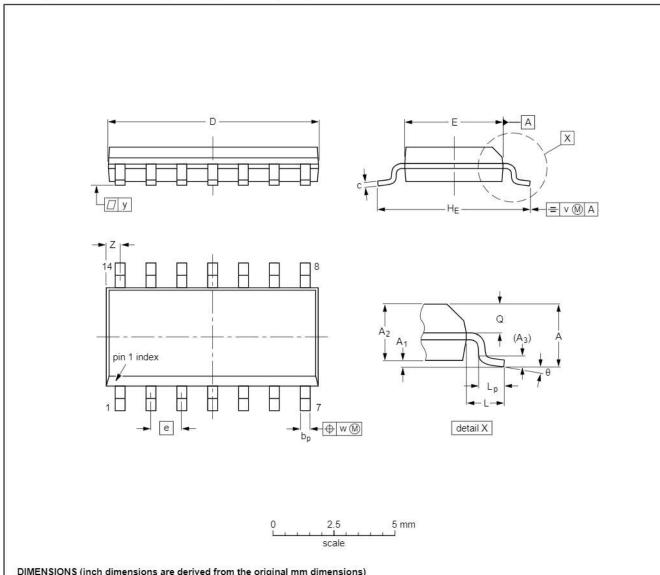
| OUTLINE | | REFE | EUROPEAN | ISSUE DATE | | |
|---------|--------|--------|-----------|------------|---------------------------------|--|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | |
| SOT27-1 | 050G04 | MO-001 | SC-501-14 | | 99-12-27 03-02-13 | |

Quad 2-input AND gate

74HC08; 74HCT08

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

| UNIT | A max. | A ₁ | A ₂ | A_3 | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | e | HE | L | Lp | Q | ٧ | w | у | Z (1) | θ |
|--------|-----------|----------------|----------------|-------|----------------|------------------|------------------|------------------|------|----------------|-------|----------------|----------------|------|------|-------|----------------|---|
| mm | 1.75 | 0.25 0.10 | 1.45 1.25 | 0.25 | 0.49 0.36 | 0.25 0.19 | 8.75 8.55 | 4.0 3.8 | 1.27 | 6.2 5.8 | 1.05 | 1.0 0.4 | 0.7 0.6 | 0.25 | 0.25 | 0.1 | 0.7 0.3 | 8 |
| inches | 0.069 | 0.010 0.004 | | 0.01 | 0.019 0.014 | 0.0100 0.0075 | 0.35 0.34 | 0.16 0.15 | 0.05 | 0.244 0.228 | 0.041 | 0.039 0.016 | 0.028 0.024 | 0.01 | 0.01 | 0.004 | 0.028 0.012 | 0 |

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

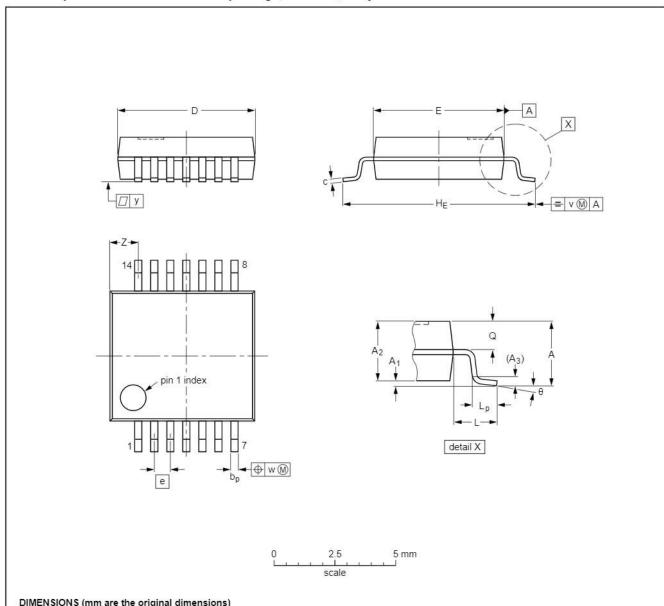
| OUTLINE | | REFER | ENCES | EUROPEAN | ICCUE DATE | | |
|----------|--------|--------|-------|------------|---------------------------------|--|--|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | | |
| SOT108-1 | 076E06 | MS-012 | | | 99-12-27 03-02-19 | | |

Quad 2-input AND gate

74HC08; 74HCT08

SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E ⁽¹⁾ | e | HE | L | Lp | Q | v | w | у | Z ⁽¹⁾ | θ |
|------|-----------|----------------|----------------|----------------|--------------|--------------|------------------|------------------|------|------------|------|--------------|------------|-----|------|-----|------------------|----|
| mm | 2 | 0.21 0.05 | 1.80 1.65 | 0.25 | 0.38 0.25 | 0.20 0.09 | 6.4 6.0 | 5.4 5.2 | 0.65 | 7.9 7.6 | 1.25 | 1.03 0.63 | 0.9 0.7 | 0.2 | 0.13 | 0.1 | 1.4 0.9 | 80 |

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | ENCES | EUROPEAN | ICCUE DATE |
|----------|-----|--------|-------|------------|----------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT337-1 | | MO-150 | | | -99-12-27 03-02-19 |

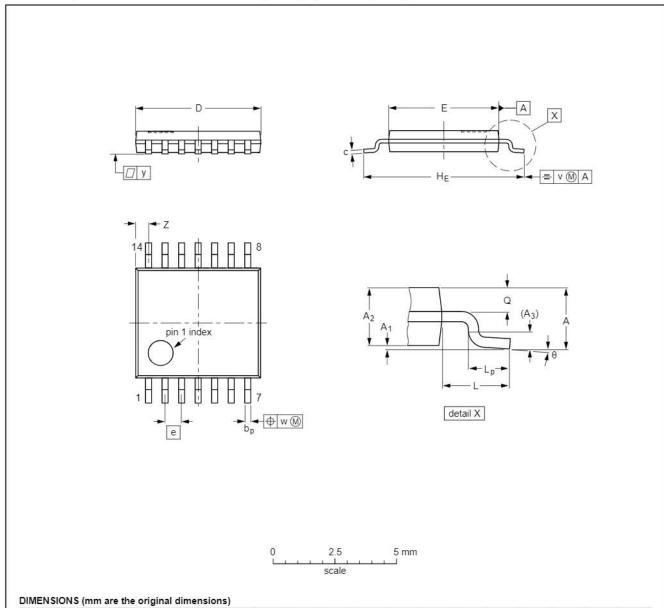
Product specification Philips Semiconductors

Quad 2-input AND gate

74HC08; 74HCT08

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



| UNIT | A max. | A ₁ | A ₂ | A ₃ | bp | С | D ⁽¹⁾ | E (2) | e | HE | L | Lp | Q | v | w | у | Z (1) | θ |
|------|-----------|----------------|----------------|----------------|--------------|------------|------------------|------------|------|------------|---|--------------|------------|-----|------|-----|--------------|----------|
| mm | 1.1 | 0.15 0.05 | 0.95 0.80 | 0.25 | 0.30 0.19 | 0.2 0.1 | 5.1 4.9 | 4.5 4.3 | 0.65 | 6.6 6.2 | 1 | 0.75 0.50 | 0.4 0.3 | 0.2 | 0.13 | 0.1 | 0.72 0.38 | 8° 0° |

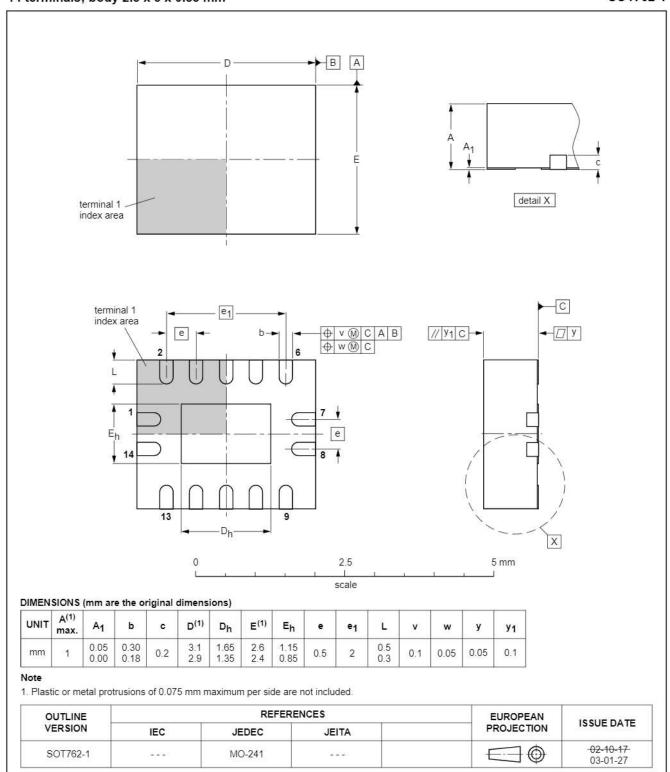
- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE | | |
|----------|-----|--------|-------|------------|---------------------------------|--|--|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE | | |
| SOT402-1 | | MO-153 | | | 99-12-27 03-02-18 | | |

Quad 2-input AND gate

74HC08; 74HCT08

DHVQFN14: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm SOT762-1



Quad 2-input AND gate

74HC08; 74HCT08

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS(1) | PRODUCT STATUS(2)(3) | DEFINITION |
|-----------------|-------------------------|-------------------------|--|
| ľ | Objective data | Development | This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice. |
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- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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